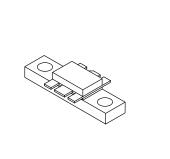
The RF Line UHF Power Transistor

The TP3005 is designed for 960 MHz base stations in both analog and digital applications. It incorporates high value emitter ballast resistors, gold metallizations and offers a high degree of reliability and ruggedness.

- Specified 26 Volts, 960 MHz Characteristics Output Power = 4.0 Watts Minimum Gain = 8.5 dB Class AB IQ = 60 mA
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

TP3005

4.0 W, 960 MHz UHF POWER TRANSISTOR NPN SILICON



CASE 319-07, STYLE 2

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCER	40	Vdc
Collector-Base Voltage	VCBO	48	Vdc
Emitter-Base Voltage	V _{EBO}	4.0	Vdc
Collector Current — Continuous	ΙC	2.0	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	25 0.2	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Operating Junction Temperature	TJ	200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case (1) at 70°C Case	R _{θJC}	7.0	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = 15 mA, R _{BE} = 75 Ω)	V _(BR) CER	45	—	-	Vdc
Emitter–Base Breakdown Voltage (I _C = 3.0 mAdc)	V _{(BR)EBO}	4.0	—	-	Vdc
Collector–Base Breakdown Voltage (I _E = 15 mAdc)	V _(BR) CBO	55	—	-	Vdc
Collector–Emitter Leakage $(V_{CE} = 26 \text{ V}, R_{BE} = 75 \Omega)$	ICER	—	—	3.0	mA
ON CHARACTERISTICS	•	•	•	•	
		4.5		400	

DC Current Gain	h _{FE}	15	—	100	—
(I _C = 0.5 Adc, V _{CE} = 10 Vdc)					

NOTE:

1. Thermal resistance is determined under specified RF operating condition.

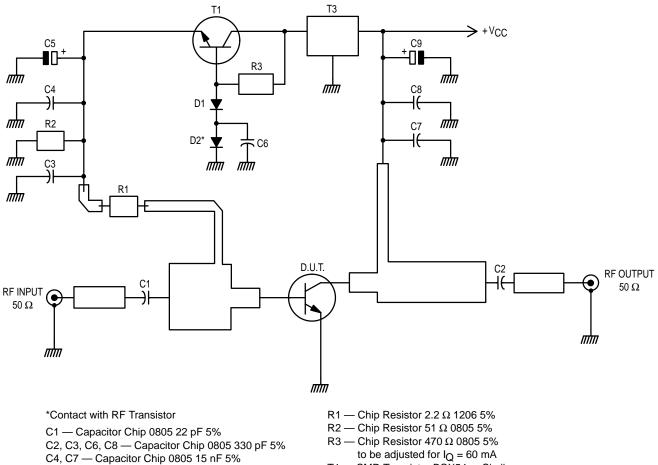
REV 6



(continued)

ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					
Output Capacitance ($V_{CB} = 26 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1.0 \text{ MHz}$)	C _{ob}	7.5	—	12.5	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain ($V_{CC} = 26 \text{ V}, P_{OUt} = 4.0 \text{ W}, I_{CQ} = 60 \text{ mA}, f = 960 \text{ MHz}$)	Gp	8.5	9.5	—	dB
Load Mismatch ($V_{CC} = 26 \text{ V}, P_{Out} = 4.0 \text{ W}, I_{CQ} = 60 \text{ mA}, \text{ Load VSWR} = 5:1, at all phase angles)$	Ψ	No Degradation in Output Power Before and After Test			
Collector Efficiency ($V_{CC} = 26 \text{ V}, P_{out} = 4.0 \text{ W}, f = 960 \text{ MHz}$)	η _c	50	55	_	%
Power Saturation P _{in} = 1.0 W	Psat	7.0	_	_	W



- C5, C9 Capacitor Chip 0805 6.0, 8.0 nF 35 V
- D1, D2 SMD Diode

- T1 SMD Transistor BCX54 or Similar
- T3 Voltage Regulator 7805
- Board Material 0.8 mm, Epoxy Glass, Cu Clad, 2 Sides,

35 µm Thick

Figure 1. 960 MHz Test Circuit

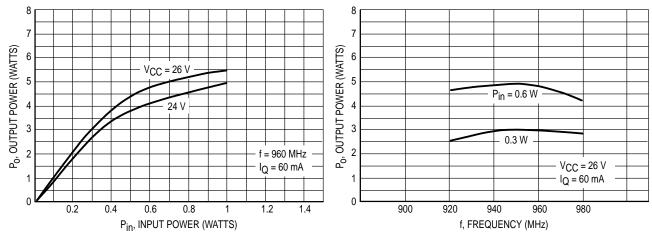


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Frequency

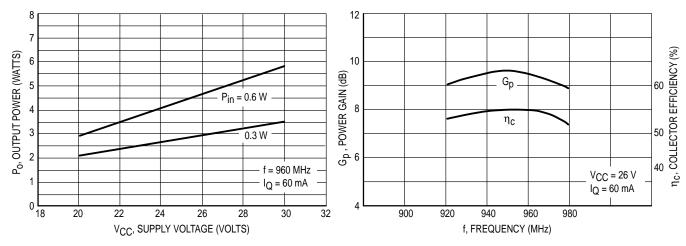
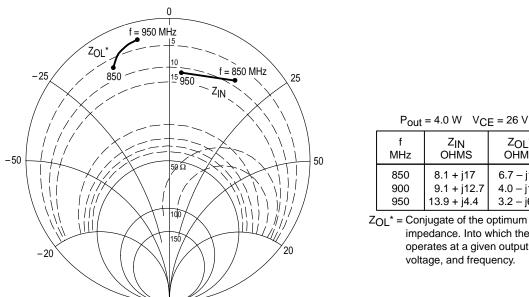


Figure 4. Output Power versus Supply Voltage

Figure 5. Typical Broadband Circuit Performance



f	Z _{IN}	Z _{OL} *		
MHz	OHMS	OHMS		
850	8.1 + j17	6.7 – j11		
900	9.1 + j12.7	4.0 – j10		
950	13.9 + j4.4	3.2 – j6.1		

 Z_{OL}^* = Conjugate of the optimum load impedance. Into which the device operates at a given output power, voltage, and frequency.

Figure 6. Series Equivalent Input/Output Impedances

MOTOROLA RF DEVICE DATA

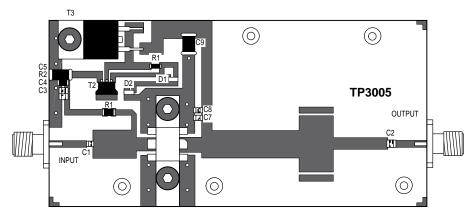
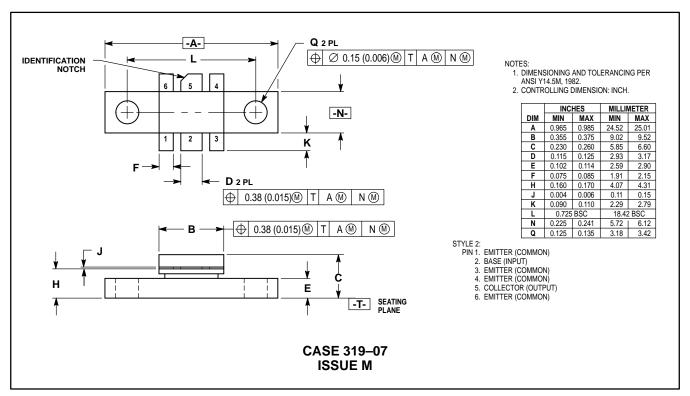


Figure 7. Test Circuit — Component Locations



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